2SC5101

Silicon NPN Triple Diffused Planar Transistor (Complement to type 2SA1909)

Application: Audio and General Purpose

■Absolute maximum ratings (Ta=25°C)

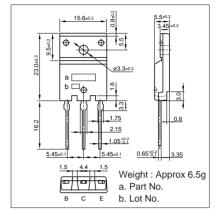
Symbol	Ratings	Unit	
Vсво	200	V	
VCEO	140	V	
VEBO	6	V	
Ic	10	А	
Ів	4	А	
Pc	80(Tc=25°C)	W	
Tj	150	°C	
Tstg	-55 to +150	°C	

■Electrical Characteristics

■Electrical Cl	naracteristics	(Ta=25°C)		
Symbol	Conditions	Ratings	Unit	
Ісво	Vcb=200V	10max	μΑ	
IEBO	VEB=6V	10max	μΑ	
V(BR)CEO	Ic=50mA	140min	V	
hfe	Vce=4V, Ic=3A	50min*		
Vce(sat)	Ic=5A, IB=0.5A	0.5max	V	
fr	Vce=12V, Ie=-0.5A	20typ	MHz	
Сов	VcB=10V, f=1MHz	250typ	рF	

*hfe Rank \overline{\overline{O}}(50 to 100), P(70 to 140), Y(90 to 180)

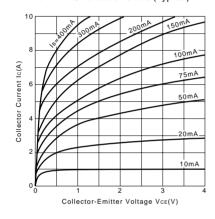
External Dimensions FM100(TO3PF)



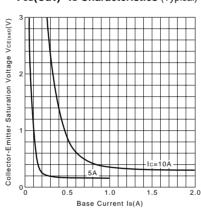
■Typical Switching Characteristics (Common Emitter)

Vcc (V)	R _L (Ω)	Ic (A)	V _{BB1} (V)	V _{BB2} (V)	I _{B1} (A)	I _{B2} (A)	ton (μs)	tstg (μs)	tf (µs)
60	12	5	10	-5	0.5	-0.5	0.24typ	4.32typ	0.40typ

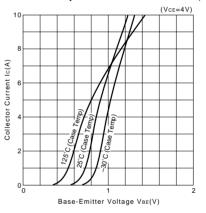
Ic-VcE Characteristics (Typical)



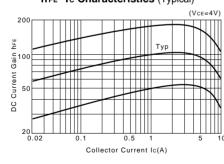
VcE(sat)-IB Characteristics (Typical)



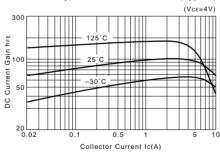
Ic-VBE Temperature Characteristics (Typical)



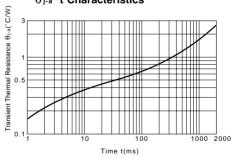
hfe-Ic Characteristics (Typical)



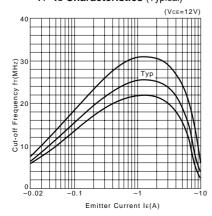
hfe-Ic Temperature Characteristics (Typical)



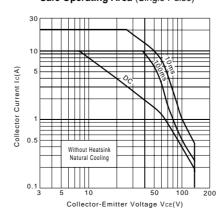
 θ_{j-a} -t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

